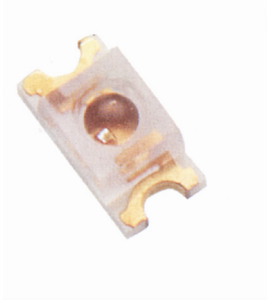




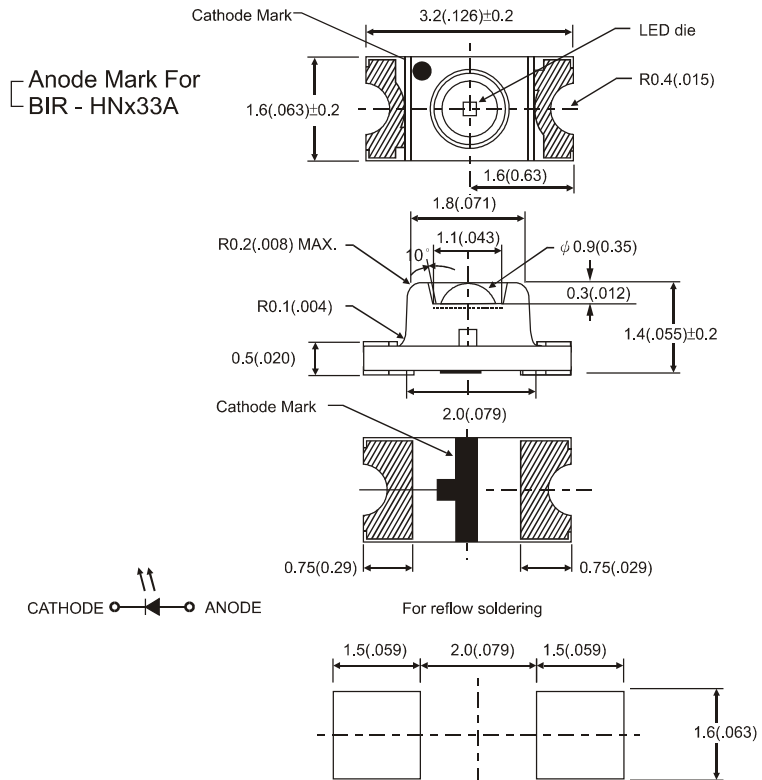
SURFACE MOUNT INFRARED EMITTING DIODES



Absolute Maximum Ratings (Ta=25°C)

	UNIT	SPEC.
IF	mA	30
IFp	A	1.0
VR	V	5
Topr	°C	-25 ~ +80
Tstg	°C	-30 ~ +85

BIR-Hxx3A Series



NOTE:
 1. All dimension are in millimeters(inches).
 2. Tolerance is ±0.10(.004") unless otherwise specified.
 3. Specifications are subject to change without notices.

Part No.	Chip			Lens Appearance	Electro-optical Data (At 20mA)					Ifp = 20mA PW = 10 μs DC = 1%		Viewing Angle 2 θ 1/2 (deg)
	Material	λp (nm)	Δ λ (nm)		V _r (V)		I _r (μA)	Radiant Power P _o (mw/sr)		T _r (ns)	T _f (ns)	
					Typ.	Max.		Min.	Typ.			
BIR-HM133A	GaAlAs	940	50	Water Clear	1.2	1.7	50	1.00	4.00	500	200	70°
BIR-HN033A	GaAlAs	880	50		1.4	2.0	50	0.71	1.20	500	200	
BIR-HO033A	GaAlAs	850	50		1.4	2.0	50	1.98	4.00	500	200	
BIR-HO133A	GaAlAs	850	50		1.4	2.0	50	1.41	3.00	500	200	